High Speed PWM Controller

FEATURES

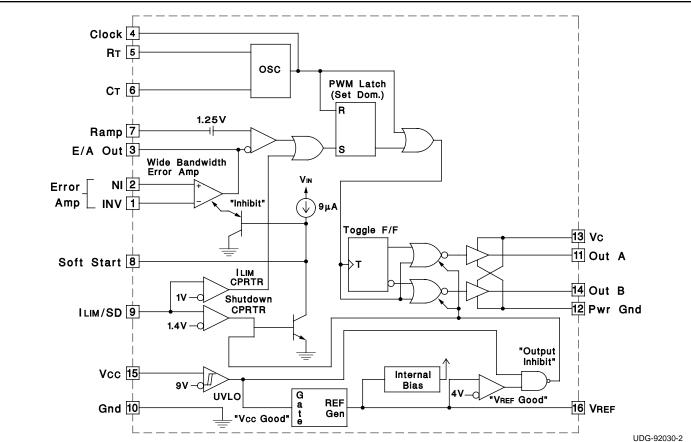
- Compatible with Voltage or Current Mode Topologies
- Practical Operation Switching Frequencies to 1MHz
- 50ns Propagation Delay to Output
- High Current Dual Totem Pole Outputs (1.5A Peak)
- Wide Bandwidth Error Amplifier
- Fully Latched Logic with Double Pulse Suppression
- Pulse-by-Pulse Current Limiting
- Soft Start / Max. Duty Cycle Control
- Under-Voltage Lockout with Hysteresis
- Low Start Up Current (1.1mA)

DESCRIPTION

The UC1825 family of PWM control ICs is optimized for high frequency switched mode power supply applications. Particular care was given to minimizing propagation delays through the comparators and logic circuitry while maximizing bandwidth and slew rate of the error amplifier. This controller is designed for use in either current-mode or voltage mode systems with the capability for input voltage feed-forward.

Protection circuitry includes a current limit comparator with a 1V threshold, a TTL compatible shutdown port, and a soft start pin which will double as a maximum duty cycle clamp. The logic is fully latched to provide jitter free operation and prohibit multiple pulses at an output. An under-voltage lockout section with 800mV of hysteresis assures low start up current. During under-voltage lockout, the outputs are high impedance.

These devices feature totem pole outputs designed to source and sink high peak currents from capacitive loads, such as the gate of a power MOSFET. The on state is designed as a high level.



BLOCK DIAGRAM

	RATINGS (Note 1)	CONNECTION DIAGRAI	MS	UC382
Output Current, Source or Sink	(Pins 11, 14) 	DIL-16 (Top View) J or N Package	<u></u>	
Analog Inputs		INV 1	16 VREF 5.1V	
	0.3V to 7V	NI 2	15 Vcc	
	0.3V to 6V	E/A Out 3	14 Out B	
	5mA Pin 3)5mA	Clock 4	13 Vc	
	1 5)	RT 5	12 Pwr Gnd	
		CT 6	11 Out A	
	65°C to +150°C	Ramp 7	10 Gnd	
	10 seconds) 300°C	Soft Start 8	9 ILIM/SD	
Note 1: All voltages are with res				
	out of part; pin numbers refer to			
DIL-16 package.	ated Circuit Databook for therma		PACKAGE PIN FU	INCTION
imitations and considerations of		PLCC-20 & LCC-20	FUNCTION	PIN
	r paonago.		N/C	
		(Top View)	N/C	1
SOIC-16 (Top View)			INV	2
SOIC-16 (Top View) DW Package		(Top View) Q & L Packages	INV NI	2 3
SOIC-16 (Top View) DW Package			INV NI E/A Out	2 3 4
· · /			INV NI E/A Out Clock	2 3 4 5
DW Package		Q & L Packages	INV NI E/A Out Clock N/C	2 3 4 5 6
DW Package	16 VREF5.1V		INV NI E/A Out Clock N/C RT	2 3 4 5 6 7
DW Package	16 VREF5.1V 15 Vcc	Q & L Packages	INV NI E/A Out Clock N/C	2 3 4 5 6
DW Package	16 VREF5.1V	Q & L Packages	INV NI E/A Out Clock N/C RT CT	2 3 4 5 6 7 8
DW Package	16 VREF5.1V 15 Vcc 14 Out B	Q & L Packages 3 2 1 20 19 4 18 5 17	INV NI E/A Out Clock N/C RT CT Ramp	2 3 4 5 6 7 8 9
DW Package INV1 NI2 E/A Out3 Clock4	16 VREF5.1V 15 VCC 14 Out B 13 VC	Q & L Packages 3 2 1 20 19 4 18 5 17 6 16	INV NI E/A Out Clock N/C RT CT Ramp Soft Start N/C ILIM/SD	2 3 4 5 6 7 8 9 10 11 12
DW Package	16 VREF5.1V 15 Vcc 14 Out B 13 Vc 12 Pwr Gnd	Q & L Packages 3 2 1 20 19 4 18 5 17 6 16 7 15	INV NI E/A Out Clock N/C RT CT Ramp Soft Start N/C ILIM/SD Gnd	2 3 4 5 6 7 8 9 10 11 12 13
DW Package INV1 NI2 E/A Out3 Clock4	16 VREF5.1V 15 VCC 14 Out B 13 VC	Q & L Packages 3 2 1 20 19 4 18 5 17 6 16 7 15 8 14	INV NI E/A Out Clock N/C RT CT CT Ramp Soft Start N/C ILIM/SD Gnd Out A	2 3 4 5 6 7 8 9 10 11 12 13 14
DW Package	16 VREF5.1V 15 Vcc 14 Out B 13 Vc 12 Pwr Gnd	Q & L Packages 3 2 1 20 19 4 18 5 17 6 16 7 15	INV NI E/A Out Clock N/C RT CT Ramp Soft Start N/C ILIM/SD Gnd Out A Pwr Gnd	2 3 4 5 6 7 8 9 10 11 12 13 14 15
DW Package INV1 NI2 E/A Out3 Clock4 RT5 CT6 Ramp7	16 VREF5.1V 15 Vcc 14 Out B 13 Vc 12 Pwr Gnd 11 Out A	Q & L Packages 3 2 1 20 19 4 18 5 17 6 16 7 15 8 14	INV NI E/A Out Clock N/C RT CT Ramp Soft Start N/C ILIM/SD Gnd Out A Pwr Gnd N/C	$ \begin{array}{c} 2\\ 3\\ 4\\ 5\\ 6\\ 7\\ 8\\ 9\\ 10\\ 11\\ 12\\ 13\\ 14\\ 15\\ 16\\ \end{array} $
DW Package INV1 NI2 E/A Out3 Clock4 RT5 CT6	16 VREF5.1V 15 Vcc 14 Out B 13 Vc 12 Pwr Gnd 11 Out A 10 Gnd	Q & L Packages 3 2 1 20 19 4 18 5 17 6 16 7 15 8 14	INV NI E/A Out Clock N/C RT CT Ramp Soft Start N/C ILIM/SD Gnd Out A Pwr Gnd N/C Vc	$ \begin{array}{c} 2\\ 3\\ 4\\ 5\\ 6\\ 7\\ 8\\ 9\\ 10\\ 11\\ 12\\ 13\\ 14\\ 15\\ 16\\ 17\\ \end{array} $
DW Package INV1 NI2 E/A Out3 Clock4 RT5 CT6 Ramp7	16 VREF5.1V 15 Vcc 14 Out B 13 Vc 12 Pwr Gnd 11 Out A 10 Gnd	Q & L Packages 3 2 1 20 19 4 18 5 17 6 16 7 15 8 14	INV NI E/A Out Clock N/C RT CT Ramp Soft Start N/C ILIM/SD Gnd Out A Pwr Gnd N/C	$ \begin{array}{c} 2\\ 3\\ 4\\ 5\\ 6\\ 7\\ 8\\ 9\\ 10\\ 11\\ 12\\ 13\\ 14\\ 15\\ 16\\ \end{array} $

THERMAL RATINGS TABLE

Package	ΘJA	ΘJC
DIL-16J	80-120	28 ⁽²⁾
DIL-16N	90 ⁽¹⁾	45
PLCC-20	43-75(1)	34
LCC-20	70-80	20 ⁽²⁾
SOIC-16	50-120 ⁽¹⁾	35

(1) Specified Θ_{JA} (junction to ambient) is for devices mounted to $5in^2$ FR4 PC board with one ounce copper where noted. When resistance range is given, lower values are for $5in^2$ aluminum PC board. Test PWB was 0.062in thick and typically used 0.635mm trace widths for power packages and 1.3mm trace widths for non-power packages with 100 x 100 mil probe land area at the end of each trace.

(2) Θ_{JC} data values stated were derived from MIL-STD-1835B. MIL-STD-1835B states that the baseline values shown are worst case (mean +2s) for a 60 x 60mil microcircuit device silicon die and applicable for devices with die sizes up to 14400 square mils. For device die sizes greater than 14400 square mils use the following values; dual-in-line, 11°C/W; flat pack 10°C/W; pin grid array, 10°C/W.

PARAMETERS	TEST CONDITIONS		UC1825 UC2825									
		MIN	TOP	MAX	MIN	TOP	MAX	UNITS				
Reference Section												
Output Voltage	$To = 25^{\circ}C$, $Io = 1mA$	5.05	5.10	5.15	5.00	5.10	5.20	V				
Line Regulation	10V < Vcc < 30V		2	20		2	20	mV				
Load Regulation	1mA < IO < 10mA		5	20		5	20	mV				
Temperature Stability*	TMIN < TA < TMAX		0.2	0.4		0.2	0.4	mV/°C				
Total Output Variation*	Line, Load, Temperature	5.00		5.20	4.95		5.25	V				
Output Noise Voltage*	10Hz < f < 10kHz		50			50		μV				
Long Term Stability*	T _J = 125°C, 1000hrs.		5	25		5	25	mV				
Short Circuit Current	VREF = 0V	-15	-50	-100	-15	-50	-100	mA				
Oscillator Section					•			•				
Initial Accuracy*	T _J = 2°C	360	400	440	360	400	440	kHz				
Voltage Stability*	10V < Vcc < 30V		0.2	2		0.2	2	%				
Temperature Stability*	TMIN < TA < TMAX		5			5		%				
Total Variation*	Line, Temperature	340		460	340		460	kHz				
Oscillator Section (cont.)	· ·	•			•			•				
Clock Out High		3.9	4.5		3.9	4.5		V				
Clock Out Low			2.3	2.9		2.3	2.9	V				
Ramp Peak*		2.6	2.8	3.0	2.6	2.8	3.0	V				
Ramp Valley*		0.7	1.0	1.25	0.7	1.0	1.25	V				
Ramp Valley to Peak*		1.6	1.8	2.0	1.6	1.8	2.0	V				
Error Amplifier Section		•	1									
Input Offset Voltage				10			15	mV				
Input Bias Current			0.6	3		0.6	3	μA				
Input Offset Current			0.1	1		0.1	1	μΑ				
Open Loop Gain	1V < V0 < 4V	60	95		60	95		dB				
CMRR	1.5V < Vсм < 5.5V	75	95		75	95		dB				
PSRR	10V < Vcc < 30V	85	110		85	110		dB				
Output Sink Current	VPIN 3 = 1V	1	2.5		1	2.5		mA				
Output Source Current	VPIN 3 = 4V	-0.5	-1.3		-0.5	-1.3		mA				
Output High Voltage	IPIN 3 = -0.5mA	4.0	4.7	5.0	4.0	4.7	5.0	V				
Output Low Voltage	IPIN 3 = 1mA	0	0.5	1.0	0	0.5	1.0	V				
Unity Gain Bandwidth*		3	5.5		3	5.5		MHz				
Slew Rate*		6	12		6	12		V/µs				

ELECTRICAL CHARACTERISTICS: Unless otherwise stated, these specifications apply for , RT = 3.65k, CT = 1nF, Vcc = 15V, -55°C<Ta<125°C for the UC1825, -40°C<Ta<85°C for the UC2825, and 0°C<Ta<70°C for the UC3825, Ta=To.

PARAMETERS	TEST CONDITIONS		UC1825 UC2825					
		MIN	TOP	MAX	MIN	TOP	MAX	UNITS
PWM Comparator Section								
Pin 7 Bias Current	VPIN 7 = 0V		-1	-5		-1	-5	μA
Duty Cycle Range		0		80	0		85	%
Pin 3 Zero DC Threshold	VPIN 7 = 0V	1.1	1.25		1.1	1.25		V
Delay to Output*			50	80		50	80	ns
Soft-Start Section								
Charge Current	VPIN 8 = 0.5V	3	9	20	3	9	20	μA
Discharge Current	VPIN 8 = 1V	1			1			mA
Current Limit / Shutdown S	ection							
Pin 9 Bias Current	0 < VPIN 9 < 4V			15			10	μA
Current Limit Threshold		0.9	1.0	1.1	0.9	1.0	1.1	V
Shutdown Threshold		1.25	1.40	1.55	1.25	1.40	1.55	V
Delay to Output			50	80		50	80	ns
Output Section					•			-
Output Low Level	IOUT = 20mA		0.25	0.40		0.25	0.40	V
	IOUT = 200mA		1.2	2.2		1.2	2.2	V
Output High Level	IOUT = -20mA	13.0	13.5		13.0	13.5		V
	IOUT = -200mA	12.0	13.0		12.0	13.0		V
Collector Leakage	Vc = 30V		100	500		10	500	μA
Rise/Fall Time*	CL = 1nF		30	60		30	60	ns
Under-Voltage Lockout Sec	tion							-
Start Threshold		8.8	9.2	9.6	8.8	9.2	9.6	V
UVLO Hysteresis		0.4	0.8	1.2	0.4	0.8	1.2	V
Supply Current Section		_			-			-
Start Up Current	Vcc = 8V		1.1	2.5		1.1	2.5	mA
ICC	VPIN 1, VPIN 7, VPIN 9 = 0V; VPIN 2 = 1V		22	33		22	33	mA

ELECTRICAL CHARACTERISTICS: Unless otherwise stated, these specifications apply for , RT = 3.65k, CT = 1nF, Vcc = 15V, -55°C<Ta<125°C for the UC1825, -40°C<Ta<85°C for the UC2825, and 0°C<Ta<70°C for the UC3825, Ta=TJ.

* This parameter not 100% tested in production but guaranteed by design.

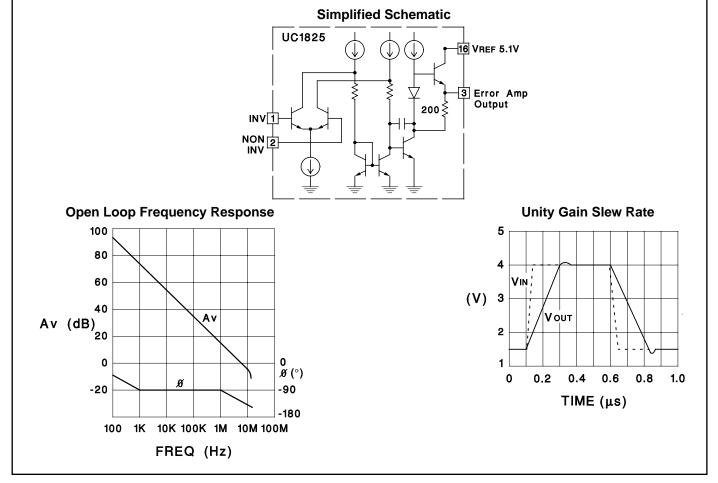
Printed Circuit Board Layout Considerations

UC1825 UC2825 UC3825

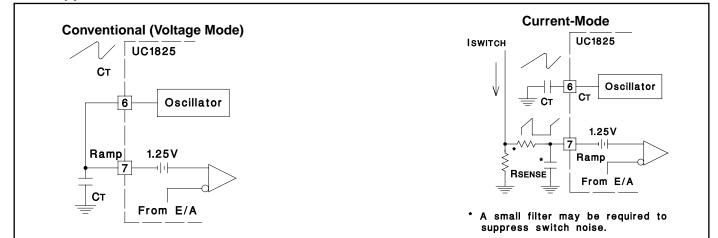
High speed circuits demand careful attention to layout and component placement. To assure proper performance of the UC1825 follow these rules: 1) Use a ground plane. 2) Damp or clamp parasitic inductive kick energy from the gate of driven MOSFETs. Do not allow the output pins to ring below ground. A series gate resistor or a shunt 1 Amp Schottky diode at the output pin will serve

this purpose. 3) Bypass Vcc, Vc, and VREF. Use 0.1μ F monolithic ceramic capacitors with low equivalent series inductance. Allow less than 1 cm of total lead length for each capacitor between the bypassed pin and the ground plane. 4) Treat the timing capacitor, CT, like a bypass capacitor.

Error Amplifier Circuit

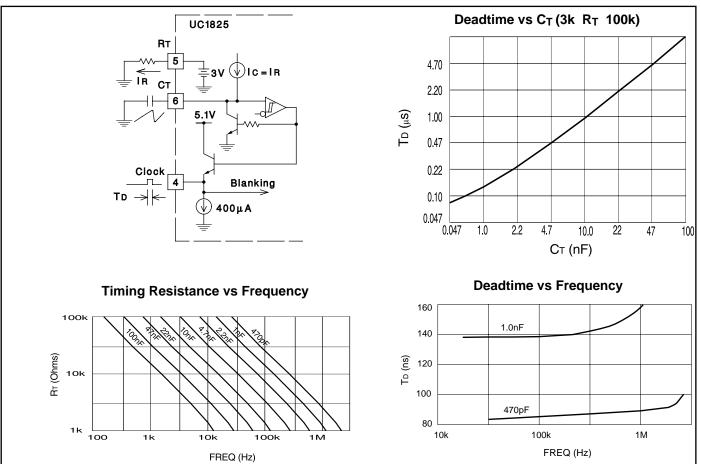


PWM Applications

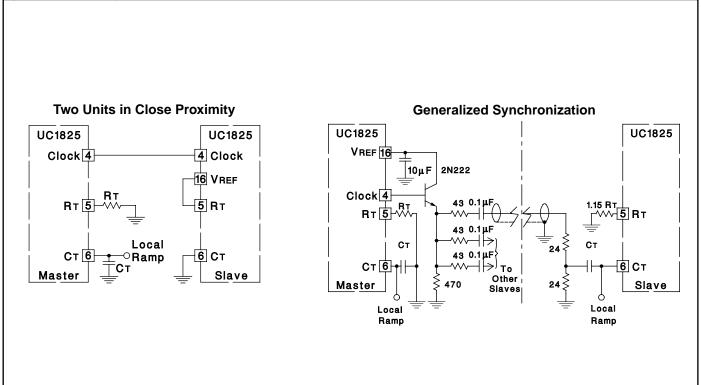


Oscillator Circuit

UC1825 UC2825 UC3825

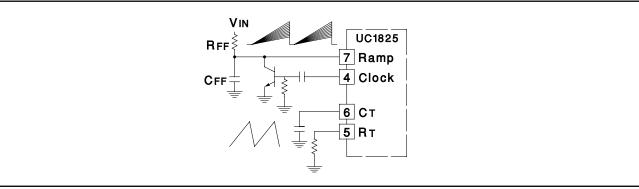


Synchronized Operation



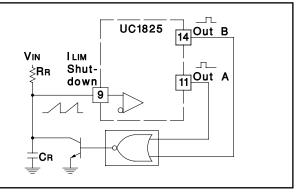
UC1825 UC2825 UC3825

Forward Technique for Off-Line Voltage Mode Application

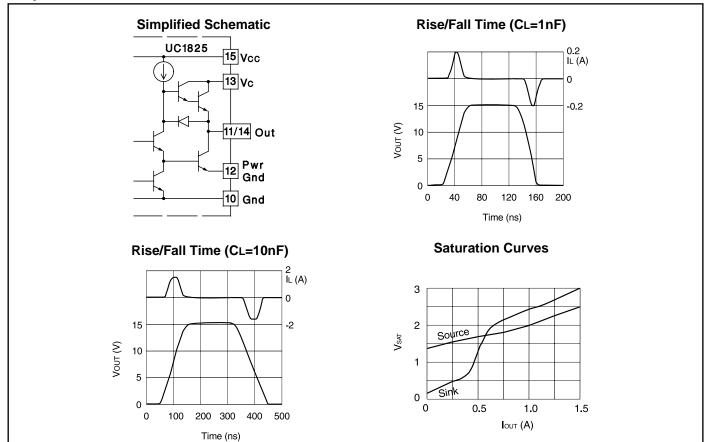


Constant Volt-Second Clamp Circuit

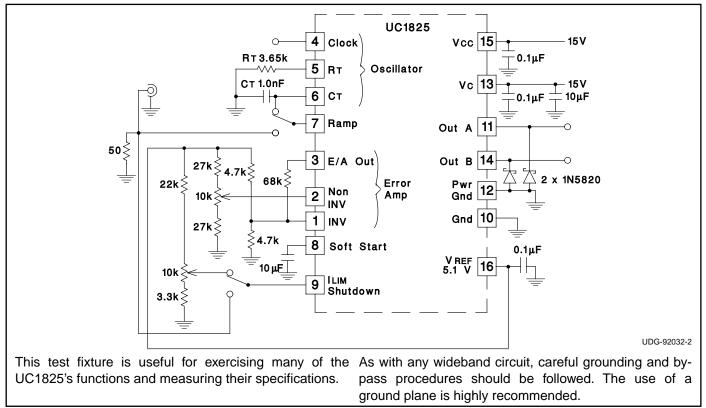
The circuit shown here will achieve a constant volt-second product clamp over varying input voltages. The ramp generator components, RT and CR are chosen so that the ramp at Pin 9 crosses the 1V threshold at the same time the desired maximum volt-second product is reached. The delay through the functional nor block must be such that the ramp capacitor can be completely discharged during the minimum deadtime.



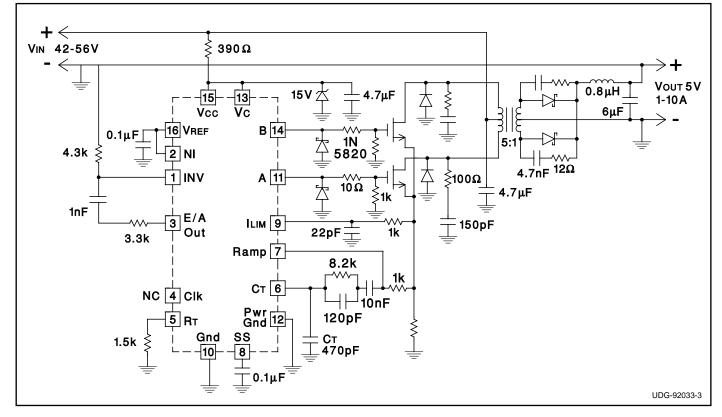
Output Section



Open Loop Laboratory Test Fixture



Design Example: 50W, 48V to 5V DC to DC Converter - 1.5MHz Clock Frequency





25-Sep-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-87681012A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 87681012A UC1825L/ 883B	Samples
5962-8768101EA	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8768101EA UC1825J/883B	Samples
5962-8768101QFA	ACTIVE	CFP	W	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8768101QF A UC1825W/883B	Samples
UC1825J	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	UC1825J	Samples
UC1825J883B	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8768101EA UC1825J/883B	Samples
UC1825L	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	UC1825L	Samples
UC1825L883B	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 87681012A UC1825L/ 883B	Samples
UC1825W883B	ACTIVE	CFP	W	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8768101QF A UC1825W/883B	Samples
UC2825DW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UC2825DW	Samples
UC2825DWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UC2825DW	Samples
UC2825DWTR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UC2825DW	Samples
UC2825DWTRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UC2825DW	Samples
UC2825J	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-40 to 85	UC2825J	Samples
UC2825N	ACTIVE	PDIP	Ν	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type	-40 to 85	UC2825N	Samples
UC2825NG4	ACTIVE	PDIP	Ν	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type	-40 to 85	UC2825N	Samples



PACKAGE OPTION ADDENDUM

25-Sep-2013

Orderable Device	Status	Package Type	Package Drawing	Pins	-	Eco Plan	Lead/Ball Finish		Op Temp (°C)	Device Marking	Samples
	(1)	51.00	U		Qty	(2)		(3)		(4/5)	
UC2825Q	ACTIVE	PLCC	FN	20	46	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 85	UC2825Q	Samples
UC2825QG3	ACTIVE	PLCC	FN	20	46	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 85	UC2825Q	Samples
UC2825QTR	OBSOLETE	PLCC	FN	20		TBD	Call TI	Call TI	-40 to 85	UC2825Q	
UC2825QTRG3	ACTIVE	PLCC	FN	20		TBD	Call TI	Call TI	-40 to 85		Samples
UC3825DW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	UC3825DW	Samples
UC3825DWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	UC3825DW	Samples
UC3825DWTR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	UC3825DW	Samples
UC3825DWTRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	UC3825DW	Samples
UC3825J	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	0 to 70	UC3825J	Samples
UC3825N	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type	0 to 70	UC3825N	Samples
UC3825NG4	ACTIVE	PDIP	Ν	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type	0 to 70	UC3825N	Samples
UC3825Q	ACTIVE	PLCC	FN	20	46	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 70	UC3825Q	Samples
UC3825QG3	ACTIVE	PLCC	FN	20	46	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 70	UC3825Q	Samples
UC3825QTR	ACTIVE	PLCC	FN	20	1000	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 70	UC3825Q	Samples
UC3825QTRG3	ACTIVE	PLCC	FN	20	1000	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 70	UC3825Q	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.



PACKAGE OPTION ADDENDUM

25-Sep-2013

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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OTHER QUALIFIED VERSIONS OF UC1825, UC2825, UC2825M, UC3825, UC3825M :

• Catalog: UC3825, UC2825, UC3825M, UC3825

- Military: UC2825M, UC1825
- Space: UC1825-SP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application

J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

W (R-GDFP-F16)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package can be hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only.
 - E. Falls within MIL STD 1835 GDFP1-F16 and JEDEC MO-092AC



LEADLESS CERAMIC CHIP CARRIER

FK (S-CQCC-N**) 28 TERMINAL SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. This package can be hermetically sealed with a metal lid.

D. Falls within JEDEC MS-004



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



MECHANICAL DATA

MPLC004A - OCTOBER 1994

PLASTIC J-LEADED CHIP CARRIER

FN (S-PQCC-J**)



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Falls within JEDEC MS-018



DW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AA.



LAND PATTERN DATA



NOTES:

A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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